```
S1: (49) 365/147.ccls.
S2: (23) S1 and light
S3: (26) S1 and (light or optical)
S4: (77565) "365"/S.ccls.
S5: (4279) ((optical$3 or light or radiation or laser) and electrical$3) near4 (program$5 or eras$3)
S6: (937) S4 and S5
S7: (150) ((optical$3 or light or radiation or laser) and electrical$3) near4 (program$5 or eras$...
S8: (20) S7 and S4
S9: (3690) (365/163,148,215,113,34,234 or 438/95 or 257/52,53,16,60).ccls.
S10: (723) S9 and laser
S11: (1050) (365/163,148,215,113,34,234).ccls.
S12: (323) S11 and laser
S13: (0) "opticalled accessible phase".ti.
S14: (2) "20050030784"
S15: (20154) memory with laser
S19: (796) chalcogenide with light
S20: (1946) chalcogenide with (light or laser or optical$3)
S21: (3690) (365/163,148,215,113,34,234 or 438/95 or 257/52,53,16,60).ccls.
S22: (104) S20 and S21
S23: (1062) chalcogenide with (light or laser or optical$3) and (read$3 or sens$3 or access$3)
S24: (93) S23 and S21
S25: (207) chalcogenide with ((light or laser or optical$3) and (read$3 or sens$3 or access$3))
S26: (34) S25 and S21
S27: (3396) (365/163,215,113,34,234 or 438/95 or 257/52,53,16,60).ccls.
S28: (570200) ((light or laser or optical$3) near6 (read$3 or sens$3 or access$3))
S29: (580) S28 and S27
S30: (389) (365/163,113,34).ccls.
S31: (86) S30 and S28
S32: (18) Combined citation search 1
S33: (7747) micro$1mirror
S34: (2) S27 and S33
S35: (9) US-5543737-S.DID. OR US-5694146-S.DID. OR US-5757446-S.DID. OR US-5166758-S.DID. OR US-5...
S36: (530) ovshinsky.in.
S37: (168) S36 and optical
S38: (28) S36 and (optical$3 with read$3)
S39: (0) S36 and (optical$3 near5 read$3) same electrical$4 near5 (program$4 or writ$3)
S40: (2) opto$1electric near4 (memory or cell) and S27
S41: (1) "6967344".pn.
S42: (2) "10426321"
S43: (352) (optical$3 near5 read$3) same electrical$4 near5 (program$4 or writ$3)
S44: (11) S43 and S21
S45: (43) read$3 with chalcogenide with (optical$3 or laser)
S46: (150) JOHNSON-bRIAN.in.
S47: (124) JOHNSON-bRIAN.in. and memory
S48: (0) JOHNSON-bRIAN.in. and "phase change"
S49: (7) JOHNSON-bRIANS.in. and "phase change"
S50: (11) ("20040178403"|"20040245603"|"4203123"|"5166758"|"5914893"|"5933365"|"6189582"|"6225142...
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|"6225142"|"6316784"|"6605821"|"6867425
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1	☑	☐	US 20040245603 A1	20041209	37	Electrically programmable memory element with improved	257/536	257/E27.004; 257/E45.002	Lowrey, Tyler et al.	☐	☐	☐	☐	☐	☐	US 20040245603		

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